FSTD3125 4-Bit Bus Switch with Level Shifting

FAIRCHILD

SEMICONDUCTOR

FSTD3125 4-Bit Bus Switch with Level Shifting

General Description

The Fairchild Switch FSTD3125 provides four high-speed CMOS TTL-compatible bus switches. The low On Resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise. A diode to $V_{\mbox{\scriptsize CC}}$ has been integrated into the circuit to allow for level shifting between 5V inputs and 3.3V outputs.

The device is organized as four 1-bit switches with separate OE inputs. When OE is LOW, the switch is ON and Port A is connected to Port B. When OE is HIGH, the switch is OPEN and a high-impedance state exists between the two ports.

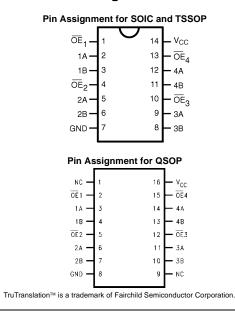
Features

- **4**Ω switch connection between two ports
- Minimal propagation delay through the switch
- Low I_{CC}
- Zero bounce in flow-through mode
- Control inputs compatible with TTL level
- TruTranslation[™] voltage translation from 5.0V inputs to 3.3V outputs

Ordering Code:

Order	Package	Package Description			
Number	Number	Package Description			
FSTD3125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
FSTD3125QSC	MQA16	16-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide			
FSTD3125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
FSTD3125MTC_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.					

Connection Diagrams



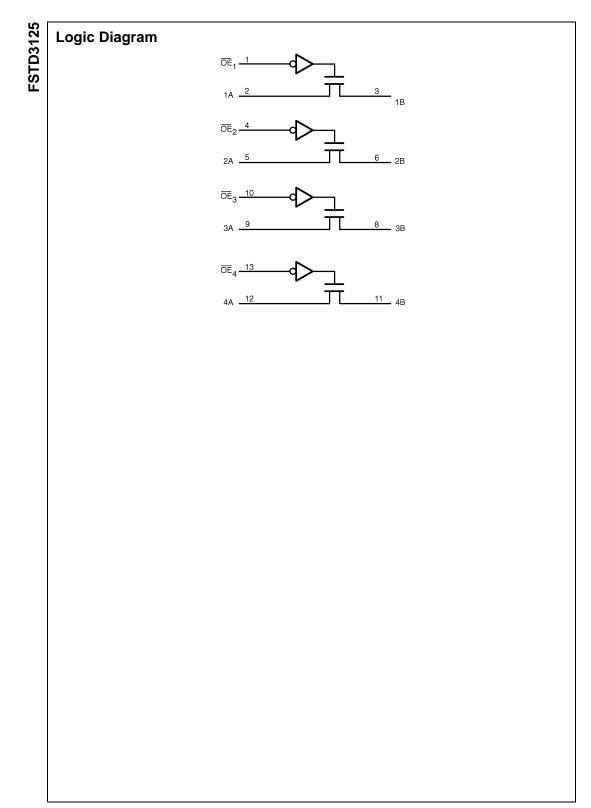
Pin Descriptions

Pin Name	Description			
$\overline{OE}_1, \overline{OE}_2, \overline{OE}_3, \overline{OE}_4$	Bus Switch Enables			
1A, 2A, 3A, 4A	Bus A			
1B, 2B, 3B, 4B	Bus B			
NC	Not Connected			

Truth Table

Inputs	Inputs/Outputs			
OE	А, В			
L	A = B			
Н	Z			

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Switch Voltage (V _S)	-0.5V to +7.0V
DC Input Voltage (VIN)(Note 2)	-0.5V to +7.0V
DC Input Diode Current (I _{IK}) $V_{IN} < 0V$	–50 mA
DC Output (I _{OUT}) Sink Current	128 mA
DC V _{CC} /GND Current (I _{CC} /I _{GND})	+/- 100 mA
Storage Temperature Range (T _{STG})	–65°C to +150 $^\circ\text{C}$

Recommended Operating Conditions (Note 3)

4.5V to 5.5V
0V to 5.5V
0V to 5.5V
0 ns/V to 5 ns/V
0 ns/V to DC
–40 °C to +85 °C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Unused control inputs must be held HIGH or LOW. They may not float.

Symbol	Parameter	V _{CC} (V)	T _A	= −40 °C to +8	5 °C	Units	Conditions
Symbol	Parameter		Min	Typ (Note 4)	Max	Units	
V _{IK}	Clamp Diode Voltage	4.5			-1.2	V	I _{IN} = -18 mA
V _{IH}	HIGH Level Input Voltage	4.5-5.5	2.0			V	
V _{OH}	HIGH Level	4.0-5.5		Figure 3		V	
V _{IL}	LOW Level Input Voltage	4.5-5.5			0.8	V	
I _I	Input Leakage Current	5.5			±1.0	μA	$0 \le V_{IN} \le 5.5V$
		0			10	μA	V _{IN} = 5.5V
I _{OZ}	OFF-STATE Leakage Current	5.5			±1.0	μA	$0 \le A, B \le V_{CC}$
R _{ON}	Switch On Resistance	4.5		4	7	Ω	$V_{IN} = 0V$, $I_{IN} = 64 \text{ mA}$
	(Note 5)	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5		35	50	Ω	V _{IN} = 2.4V, I _{IN} = 1 5mA
I _{CC}	Quiescent Supply Current	5.5			1.5		$OE_1 = OE_2 = GND$
					1.5	mA	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
					10	μΑ	$OE_1 = OE_2 = V_{CC}$
							$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
ΔI_{CC}	Increase in I _{CC} per Input	5.5			2.5	mA	One Input at 3.4V.
							Other Inputs at V _{CC} or GND

DC Electrical Characteristics

Note 4: Typical values are at V_{CC} = 5.0V and T_A = +25 ^{\circ}C

Note 5: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

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FSTD3125

AC Electrical Characteristics

Symbol	Parameter	$\label{eq:transform} \begin{split} T_{A} &= -40 \ ^{\circ}\text{C} \ to \ +85 \ ^{\circ}\text{C}, \\ C_{L} &= 50 \text{pF}, \ \text{RU} = \text{RD} = 500 \Omega \\ \hline V_{CC} &= 4.5 - 5.5 \text{V} \end{split}$		Units	Conditions	Figure Number
		Min	Max			
t _{PHL} , t _{PLH}	Propagation Delay Bus to Bus (Note 6)		0.25	ns	V _I = OPEN	Figures 1, 2
t _{PZH} , t _{PZL}	Output Enable Time	1.0	6.1	ns	$V_I = 7V$ for t_{PZL} $V_I = OPEN$ for t_{PZH}	Figures 1, 2
t _{PHZ} , t _{PLZ}	Output Disable Time	1.5	6.4	ns	$V_I = 7V$ for t_{PLZ} $V_I = OPEN$ for t_{PHZ}	Figures 1, 2

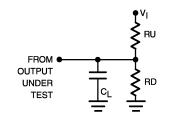
Note 6: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On Resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Capacitance (Note 7)

Symbol	Parameter	Тур	Max	Units	Conditions
C _{IN}	Control Pin Input Capacitance	3		pF	$V_{CC} = 5.0V$
C _{I/O}	Input/Output Capacitance	6		pF	$V_{CC}, \overline{OE} = 5.0V$

Note 7: $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested.

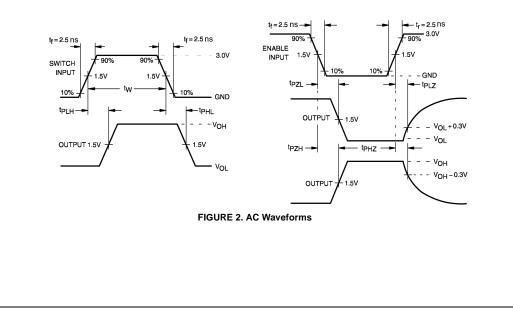
AC Loading and Waveforms



Note: Input driven by 50 Ω source terminated in 50 Ω

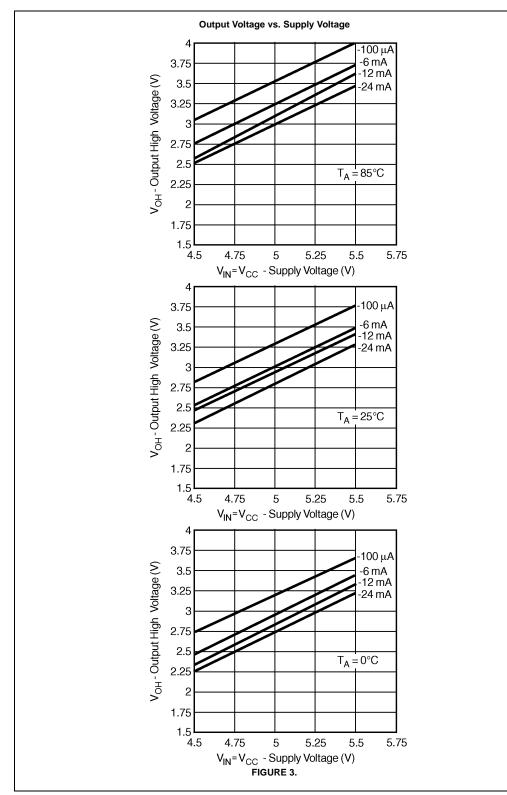
Note: C_L includes load and stray capacitance Note: Input PRR = 1.0 MHz, t_W = 500ns

FIGURE 1. AC Test Circuit



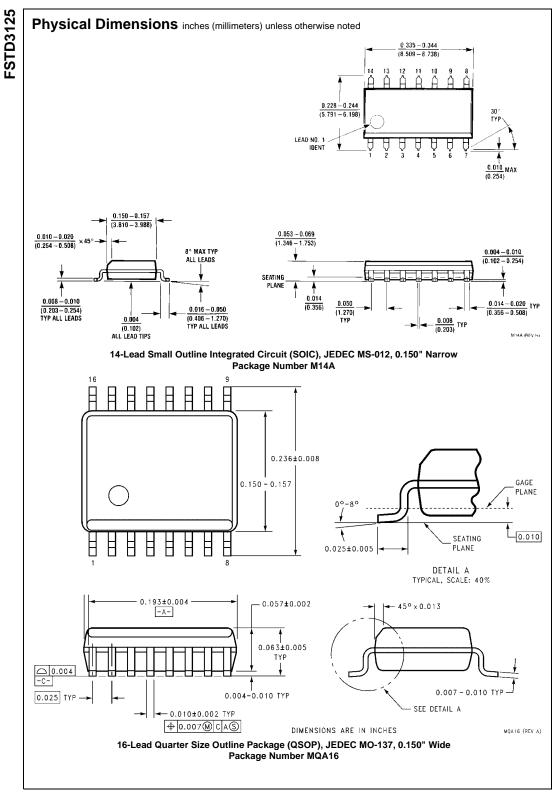
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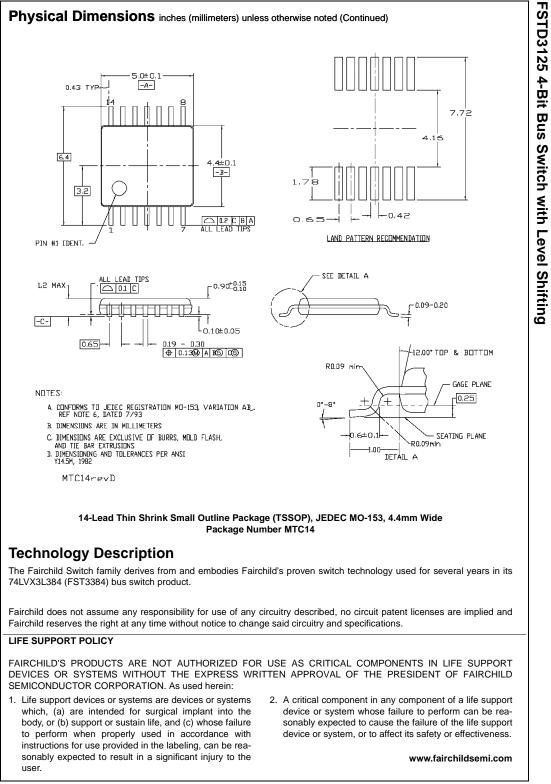


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